Record Nr. UNINA9910815403003321 Terrestrial neutron-induced soft errors in advanced memory devices // **Titolo** Takashi Nakamura ... [et al.] Pubbl/distr/stampa Hackensack, NJ,: World Scientific, c2008 **ISBN** 1-281-93005-9 9786611930059 981-277-882-9 Edizione [1st ed.] Descrizione fisica 1 online resource (364 p.) Altri autori (Persone) NakamuraTakashi <1939-> Disciplina 621.39732 Soggetti Semiconductor storage devices Neutron irradiation Radiation dosimetry **Nuclear physics** Lingua di pubblicazione Inglese **Formato** Materiale a stampa Livello bibliografico Monografia Note generali Description based upon print version of record. Nota di bibliografia Includes bibliographical references (p. 291-315) and index. Nota di contenuto CONTENTS; Preface; About the Authors; Chapter 1 Introduction; 1.1 Background; 1.2 General Description of the SEE Mechanism; 1.3 Overview of Quantitative Evaluation Methods; Chapter 2 Terrestrial Neutron Spectrometry and Dosimetry; 2.1 Introduction; 2.2 Neutron Detection Method; 2.2.1 Multi-moderator spectrometer (Bonner Ball, Bonner sphere); 2.2.2 Organic liquid scintillation spectrometer; 2.2.3 Dose equivalent counter (rem counter); 2.2.4 Phoswich-type detector; 2.3 Experimental Procedure; 2.3.1 Sequential neutron measurements on the ground at sea level 2.3.2 Neutron measurements aboard an airplane and at mountain level2.3.3 Data analysis; 2.4 Results and Discussions; 2.4.1 Atmospheric pressure effect; 2.4.2 Neutron energy spectra; 2.4.3 Time-sequential results of neutron ambient dose equivalent rates: 2.4.4 Average values of neutron flux and ambient dose equivalent; 2.4.5 Variation with latitude, altitude and solar activity; 2.4.6 Calculation of the cosmic-ray neutron spectrum; 2.5 Concluding

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Sommario/riassunto

Terrestrial neutron-induced soft errors in semiconductor memory devices are currently a major concern in reliability issues. Understanding the mechanism and quantifying soft-error rates are primarily crucial for the design and quality assurance of semiconductor memory devices. This book covers the relevant up-to-date topics in terrestrial neutron-induced soft errors, and aims to provide succinct knowledge on neutron-induced soft errors to the readers by presenting several valuable and unique features. <i>Sample Chapter(s) </i>

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Chapter 1: Introduction (238 KB)

Table A.30 mentioned in Ap